

Quad Monolithic SPST CMOS Analog Switches

DESCRIPTION

Featuring low on-resistance (60 Ω) and fast switching (130 ns), the DG308A is supplied in the "normally open" configuration while DG309 is supplied "normally closed". Input thresholds are high voltage CMOS compatible.

Designed with the Vishay Siliconix PLUS-40 CMOS process to combine low power dissipation with a high breakdown voltage rating of 44 V, each switch conducts equally well in both directions when on, and blocks up to the supply voltage when off. An epitaxial layer prevents latch up.

The DG308B, DG309B upgrades are recommended for new designs.

FEATURES

± 15 V analog input range

• Low on-resistance: 60 Ω · Fast switching: 130 ns

· Low power dissipation: 30 nW

CMOS logic compatible

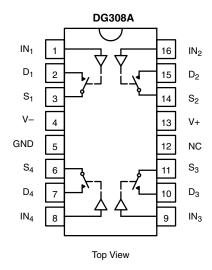
BENEFITS

- Full rail-to-rail analog signal range
- Low signal error
- Wide dynamic range
- Single or dual supply capability
- Static protected logic inputs
- Space savings (TSSOP)

APPLICATIONS

- Portable and battery powered instrumentation
- · Communication systems
- Computer peripherals
- High-speed multiplexing

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



For SPST Switches per Package

TRUTH TABLE						
Logic	DG308A	DG309				
0	OFF	ON				
1	ON	OFF				

Logic "0" $\leq 3.5 \text{ V}$ Logic "1" ≥ 11 V

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply

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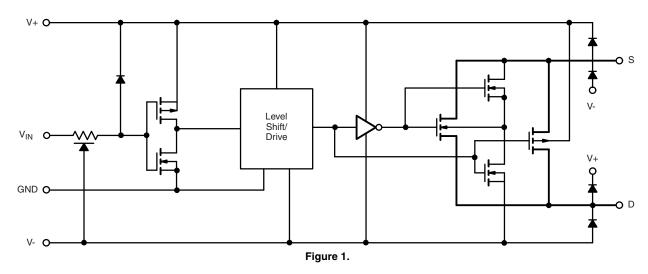
ORDERING INFORMATION					
Temp. Range	Package	Part Number			
		DG308ACJ			
0 °C to 70 °C	16-Pin Plastic DIP	DG308ACJ-E3			
		DG309CJ			
		DG309CJ-E3			
		DG308ADY			
		DG308ADY-E3			
	16-Pin Narrow SOIC	DG308ADY-T1			
		DG308ADY-T1-E3			
		DG309DY			
		DG309DY-E3			
		DG309DY-T1			
- 40 °C to 85 °C		DG309DY-T1-E3			
- 40 0 10 65 0		DG308ADQ			
		DG308ADQ-E3			
		DG308ADQ-T1			
	16-Pin TSSOP	DG308ADQ-T1-E3			
	10-1 III 1330F	DG309DQ			
		DG309DQ-E3			
		DG309DQ-T1			
		DG309DQ-T1-E3			

ABSOLUTE MAXIM	IUM RATINGS			
Parameter		Limit	Unit	
Voltages Referenced V+ to V	V-	44		
GND		25	V	
Digital Inputs ^a , V _S , V _D		(V-) - 2 to (V+) + 2 or 20 mA, whichever occurs first	v	
Current, Any Terminal Except S or D		30		
0 11 0 1	S or D	20	mA	
Continuous Current	(Pulsed at 1 ms, 10 % duty cycle max.)	70	7	
Ctorogo Tomporatura	(AK Suffix)	- 65 to 150	°C	
Storage Temperature	(CJ, DY and DQ Suffix)	- 65 to 125		
	16-Pin Plastic DIP ^c	470		
Power Dissipation ^b	16-Pin Narrow SOIC and TSSOP ^e	600	mW	
	16-Pin CerDIP ^d	900	7	

- Notes: a. Signals on S_X , D_X , or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 12 mW/°C above 75 °C.
- d. Derate 6.5 mW/°C above 25 °C.
- e. Derate 7.6 mW/°C above 75 °C.



SCHEMATIC DIAGRAM (Typical Channel)



SPECIFICATIONS ^a									
		Test Conditions Unless Specified V+ = 15 V, V- = - 15 V			A Suffix - 55 °C to 125°C		C, D Suffix		
Parameter	Symbol	$V_{IN} = 3.5 \text{ V or } 11 \text{ V}^{f}$	Temp.b	Typ.c	Min. ^d	Max. ^d	Min.d	Max.d	Unit
Analog Switch				I.		I.	<u> </u>		
Analog Signal Range ^e	V _{ANALOG}		Full		- 15	15	- 15	15	V
Drain-Source On-Resistance	R _{DS(on)}	$V_D = \pm 10 \text{ V}, I_S = 1 \text{ mA}$	Room Full	60		100 150		100 125	Ω
Source Off Leakage Current	I _{S(off)}	$V_S = \pm 14 \text{ V}, V_D = \pm 14 \text{ V}$	Room Full	± 0.1	- 1 100	1 100	- 5 - 100	5 100	
Drain Off Leakage Current	I _{D(off)}	$V_D = \pm 14 \text{ V}, V_S = \pm 14 \text{ V}$	Room Full	± 0.1	- 1 100	1 100	- 5 - 100	5 100	nA
Drain On Leakage Current	I _{D(on)}	$V_D = V_S = \pm 14 \text{ V}$	Room Full	± 0.1	- 1 100	1 100	- 5 - 200	5 200	
Digital Control									
Input Current with Input Voltage High	I _{INH}	V _{IN} = 15 V	Full	0.001		1		1	μА
Input Current with Input Voltage Low	I _{INL}	V _{IN} = 0 V	Full	- 0.001	- 1		- 1		μΑ
Input Capacitance	C _{IN}		Room	8					pF
Dynamic Characteristics									
Turn-On Time	t _{ON}	see figure 2	Room	130		200		200	ns
Turn-Off Time	t _{OFF}	300 liguro 2	Room	90		150		150	113
Charge Injection	Q	$C_L = 0.01 \mu F, R_{gen} = 0 \Omega, V_{gen} = 0 V,$	Room	- 10					рС
Source-Off Capacitance	C _{S(off)}		Room	11					
Drain-Off Capacitance	C _{D(off)}	$f = 140 \text{ kHz}, V_S, V_D = 0 \text{ V}$	Room	8					pF
Channel-On Capacitance	C _{D(on)}		Room	27					
Off-Isolation [†]	OIRR	$R_L = 75 \Omega$, $V_S = 2 V_{p-p}$, $f = 500 \text{ kHz}$	Room	78					dB

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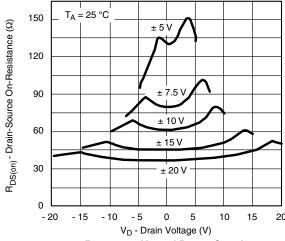
SPECIFICATIONS ^a									
		Test Conditions Unless Specified V+ = 15 V, V- = - 15 V			_	uffix to 125°C	C, D	Suffix	
Parameter	Symbol	$V_{IN} = 3.5 \text{ V or } 11 \text{ V}^{f}$	Temp.b	Typ. ^c	Min. ^d	Max. ^d	Min. ^d	Max. ^d	Unit
Power Supplies									
Positive Supply Current	I+	all channels on or off	Room Full	0.001		10 100		10 100	
Negative Supply Current	I-	V _{IN} = 0 V or 15 V	Room Full	- 0.001	- 10 - 100		- 100		μΑ

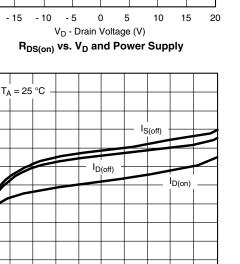
Notes:

- a. Refer to PROCESS OPTION FLOWCHART.
- b.Room = 25 $^{\circ}$ C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e.Guaranteed by design, not subject to production test.
- f. V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

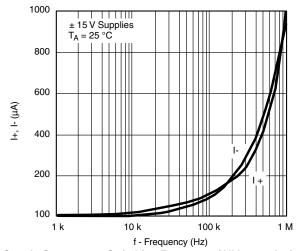
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



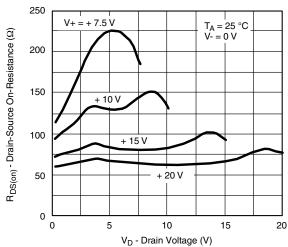


 V_D or V_S - Drain or Source Voltage (V) Leakage Currents vs. Analog Voltage

- 3 0 3 6 9



Supply Currents vs. Switching Frequency (All Inputs Active)



 $R_{DS(on)}$ vs. V_D and Power Supply Voltage

20

10

0

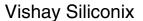
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- 20

- 30

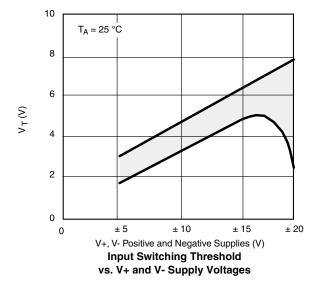
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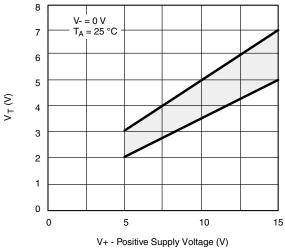
Is, In (pA)



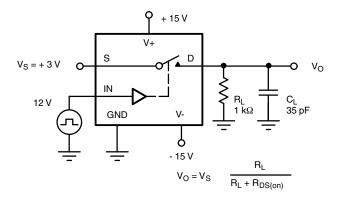


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





V+ - Positive Supply Voltage (V)
Input Switching Threshold vs. Positive
Supply Voltage



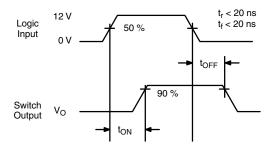


Figure 2. Switching Time

APPLICATIONS

Single Supply Operation

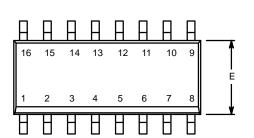
The DG308A and DG309 will switch positive analog signals while using a single positive supply. This will allow use in many applications where only one supply is available. The trade-offs or performance given up while using single supplies are:

1) increased $R_{DS(on)}$ and 2) slower switching speed. As stated in the absolute maximum ratings section of the data sheet, the analog voltage should not go above or below the supply voltages which in single supply operation are V+ and 0 V.

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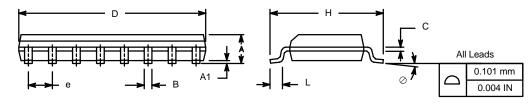
SOIC (NARROW): 16-LEAD JEDEC Part Number: MS-012



	MILLIMETERS		INC	HES	
Dim	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A ₁	0.10	0.20	0.004	0.008	
В	0.38	0.51	0.015	0.020	
С	0.18	0.23	0.007	0.009	
D	9.80	10.00	0.385	0.393	
E	3.80	4.00	0.149	0.157	
е	1.27	BSC	0.050	BSC	
Н	5.80	6.20	0.228	0.244	
L	0.50	0.93	0.020	0.037	
0	0°	8°	0°	8°	
FCN: S-03946—Rev F 09-Jul-01					

ECN: S-03946—Rev. F, 09-Jul-01

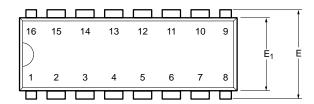
DWG: 5300

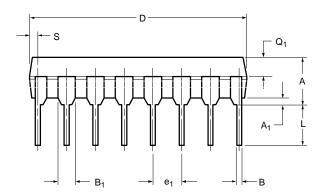


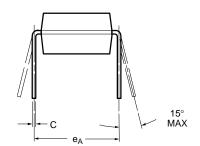
Document Number: 71194 www.vishay.com 02-Jul-01



PDIP: 16-LEAD





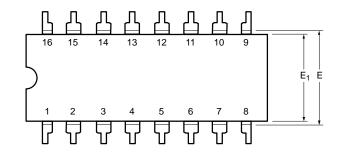


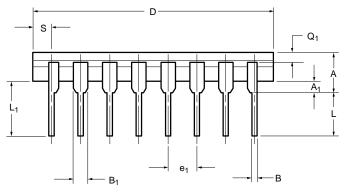
	MILLIN	IETERS	INC	HES	
Dim	Min	Max	Min	Max	
Α	3.81	5.08	0.150	0.200	
A ₁	0.38	1.27	0.015	0.050	
В	0.38	0.51	0.015	0.020	
B ₁	0.89	1.65	0.035	0.065	
С	0.20	0.30	0.008	0.012	
D	18.93	21.33	0.745	0.840	
E	7.62	8.26	0.300	0.325	
E ₁	5.59	7.11	0.220	0.280	
e ₁	2.29	2.79	0.090	0.110	
e _A	7.37	7.87	0.290	0.310	
L	2.79	3.81	0.110	0.150	
Q_1	1.27	2.03	0.050	0.080	
S	0.38	1.52	.015	0.060	
ECN: S-03946—Rev. D, 09-Jul-01 DWG: 5482					

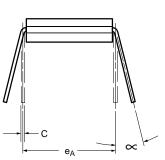
Document Number: 71261 www.vishay.com 06-Jul-01 www.vishay.com



CERDIP: 16-LEAD





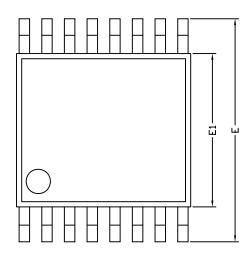


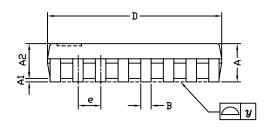
	MILLIN	IETERS	INC	HES
Dim	Min	Max	Min	Max
Α	4.06	5.08	0.160	0.200
A ₁	0.51	1.14	0.020	0.045
В	0.38	0.51	0.015	0.020
B ₁	1.14	1.65	0.045	0.065
С	0.20	0.30	0.008	0.012
D	19.05	19.56	0.750	0.770
Е	7.62	8.26	0.300	0.325
E ₁	6.60	7.62	0.260	0.300
e ₁	2.54	BSC	0.100	BSC
\mathbf{e}_{A}	7.62	BSC	0.300	BSC
┙	3.18	3.81	0.125	0.150
L ₁	3.81	5.08	0.150	0.200
Q_1	1.27	2.16	0.050	0.085
S	0.38	1.14	0.015	0.045
∞	0°	15°	0°	15°
ECN: S-0 DWG: 54	3946—Rev. 0 103	G, 09-Jul-01		

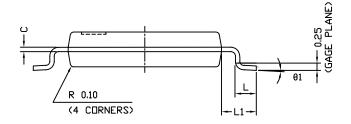
www.vishay.com Document Number: 71282 03-Jul-01



TSSOP: 16-LEAD







	DII	MENSIONS IN MILLIMETE	RS
Symbols	Min	Nom	Max
А	=	1.10	1.20
A1	0.05	0.10	0.15
A2	=	1.00	1.05
В	0.22	0.28	0.38
С	=	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
е	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
у	=	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D. 23-0	Oct-06	<u> </u>	

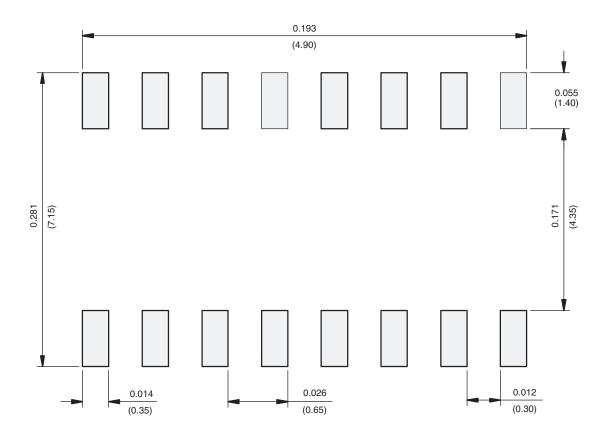
ECN: S-61920-Rev. D, 23-Oct-06

DWG: 5624

Document Number: 74417 www.vishay.com 23-Oct-06 1



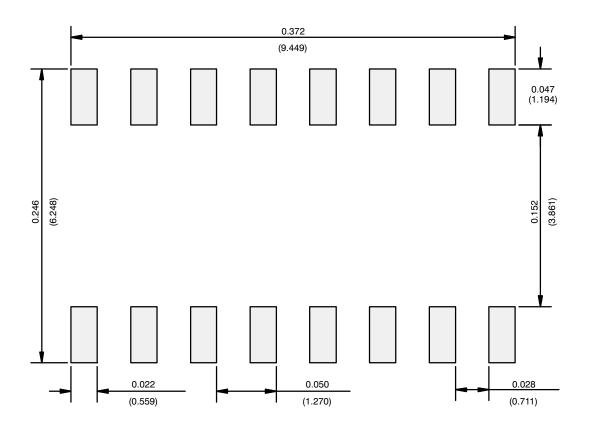
RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads Dimensions in inches (mm)



RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads Dimensions in Inches/(mm)

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